NSN 5961-00-937-0390

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-937-0390 **Inclosure Material:** Metal **Overall Length:** Between 0.333 inches and 0.359 inches Overall Diameter: Between 0.761 inches and 0.769 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 110.0 breakdown voltage, collector-to-base, emitter open and 6.0 breakdown voltage, emitter-to-base, collector open and 100.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 7.50 amperes source cutoff current and 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 666.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure:** Demilitarization: No